

S-5743 A Series

125°C OPERATION HIGH-WITHSTAND VOLTAGE HIGH-SPEED BIPOLAR HALL EFFECT LATCH IC

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Rev.1.4 00

This IC, developed by CMOS technology, is a high-accuracy hall effect latch IC that operates with high temperature and high-withstand voltage.

The output voltage changes when this IC detects the intensity level of magnetic flux density and a polarity change. Using this IC with a magnet makes it possible to detect the rotation status in various devices.

This IC includes an output current limit circuit.

High-density mounting is possible by using the small SOT-23-3S package.

Due to its high-accuracy magnetic characteristics, this IC enables the user to reduce the operational variation in the system.

ABLIC Inc. offers a "magnetic simulation service" that provides the ideal combination of magnets and our Hall effect ICs for customer systems. Our magnetic simulation service will reduce prototype production, development period and development costs. In addition, it will contribute to optimization of parts to realize high cost performance. For more information regarding our magnetic simulation service, contact our sales office.

Features

Pole detection:	Bipolar latch
 Output logic^{*1}: 	Vout = "L" at S pole detection
	Vout = "H" at S pole detection
Output form:	Nch open-drain output
 Magnetic sensitivity^{*1}: 	B _{OP} = 0.5 mT typ.
	B _{OP} = 1.5 mT typ.
	B _{OP} = 2.2 mT typ.
	B _{OP} = 3.0 mT typ.
 Chopping frequency: 	$f_{\rm C}$ = 500 kHz typ.
 Output delay time: 	t _D = 8.0 μs typ.
 Power supply voltage range: 	V _{DD} = 2.7 V to 26.0 V
 Built-in regulator 	
 Built-in output current limit circuit 	
 Operation temperature range: 	Ta = -40°C to +125°C
 Lead-free (Sn 100%), halogen-free 	

*1. The option can be selected.

Applications

- Power tool
- Home appliance
- DC brushless motor
- Housing equipment
- Industrial equipment

Package

• SOT-23-3S

Block Diagram

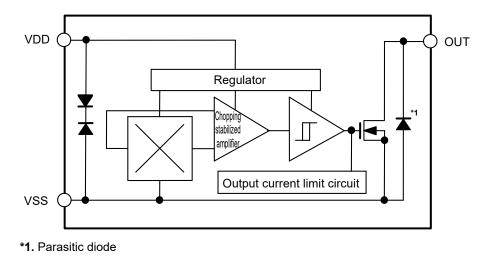
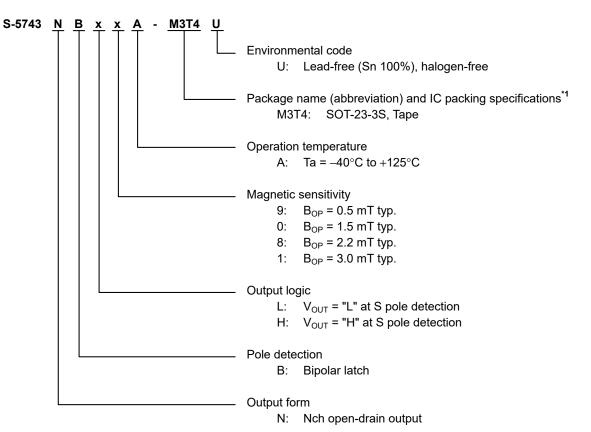


Figure 1

Product Name Structure

1. Product name



*1. Refer to the tape drawing.

2. Package

 Table 1
 Package Drawing Codes

Package Name	Dimension	Таре	Reel
SOT-23-3S	MP003-D-P-SD	MP003-D-C-SD	MP003-D-R-SD

3. Product name list

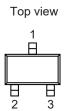
Product Name	Output Form	Pole Detection	Output Logic	Magnetic Sensitivity (B _{OP})
S-5743NBL9A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "L" at S pole detection	0.5 mT typ.
S-5743NBL0A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "L" at S pole detection	1.5 mT typ.
S-5743NBL8A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "L" at S pole detection	2.2 mT typ.
S-5743NBL1A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "L" at S pole detection	3.0 mT typ.
S-5743NBH9A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "H" at S pole detection	0.5 mT typ.
S-5743NBH1A-M3T4U	Nch open-drain output	Bipolar latch	V _{OUT} = "H" at S pole detection	3.0 mT typ.

Table 2

Remark Please contact our sales office for products other than the above.

Pin Configuration

1. SOT-23-3S



Pin No.	Symbol	Description
1	VSS	GND pin
2	VDD	Power supply pin
3	OUT	Output pin

Table 3

Figure 2

■ Absolute Maximum Ratings

Table 4

		(Ta = +25°C unless otherwise s	specified)
Item	Symbol	Absolute Maximum Rating	Unit
Power supply voltage	V _{DD}	$V_{SS} - 0.3$ to $V_{SS} + 28.0$	V
Output current	Іоит	20	mA
Output voltage	Vout	Vss - 0.3 to Vss + 28.0	V
Operation ambient temperature	T _{opr}	-40 to +125	°C
Storage temperature	T _{stg}	-40 to +150	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Thermal Resistance Value

Table 5								
Item	Symbol	Conditi	on	Min.	Тур.	Max.	Unit	
Junction-to-ambient thermal resistance*1			Board A	-	200	-	°C/W	
	θја		Board B	_	165	1	°C/W	
			Board C	_	_	-	°C/W	
			Board D	_	I	١	°C/W	
			Board E	_	_	_	°C/W	

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "**■ Power Dissipation**" and "**Test Board**" for details.

Table 6

Electrical Characteristics

		(Ta = +25°C, V _{DD} = 12.0 \	/, Vss =	0 V unle	ess othe	erwise sp	ecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	V _{DD}	_	2.7	12.0	26.0	V	-
Current consumption	IDD	Average value	_	3.0	4.0	mA	1
Output voltage	V _{OUT}	I _{OUT} = 10 mA	_	—	0.4	V	2
Leakage current	ILEAK	Output transistor Nch, Vout = 26.0 V	_	—	1	μA	3
Output limit current	I _{OM}	V _{OUT} = 12.0 V	22	_	70	mA	3
Output delay time	t _D	-	_	8.0	-	μs	—
Chopping frequency	fc	_	-	500	-	kHz	-
Start up time	t _{PON}	_	_	20	-	μs	4
Output rise time	t _R	C = 20 pF, R = 820 Ω	_	_	2.0	μs	5
Output fall time	t _F	C = 20 pF, R = 820 Ω	_	_	2.0	μs	5

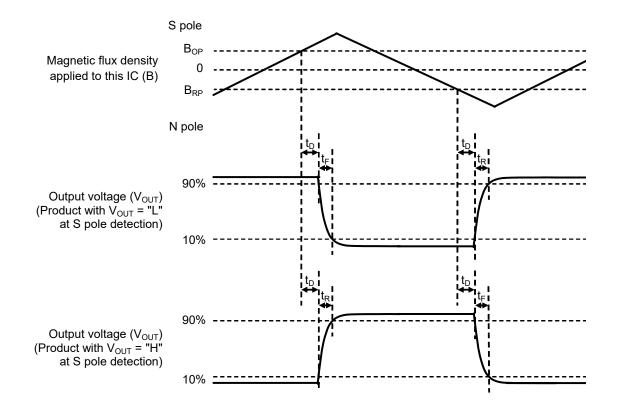


Figure 3 Operation Timing

Magnetic Characteristics

1. Product with $B_{OP} = 0.5 \text{ mT typ.}$

Table 7

			(Ta = +25	°C, V _{DD} = 1	12.0 V, Vss	= 0 V unle	ss other	wise specified)
ltem		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	-0.5	0.5	1.5	mT	4
Release point*2	N pole	BRP	-	-1.5	-0.5	0.5	mT	4
Hysteresis width*3		B _{HYS}	$B_{HYS} = B_{OP} - B_{RP}$	-	1.0	Ι	mT	4

2. Product with $B_{OP} = 1.5 \text{ mT typ.}$

(Ta = +25°C, V_{DD} = 12.0 V, V_{SS} = 0 V unless otherwise specified) Test Circuit Symbol Condition Max. Unit Item Min. Typ. Operation point*1 S pole 0.5 1.5 2.5 mT 4 BOP _ Release point*2 N pole 4 Brp _ -2.5 -1.5 -0.5 mT Hysteresis width*3 BHYS 3.0 4 BHYS = BOP - BRP mT

Table 8

3. Product with $B_{OP} = 2.2 \text{ mT typ.}$

Table 9

(Ta = +25°C, V_{DD} = 12.0 V, V_{SS} = 0 V unless otherwise specified) Symbol Item Condition Min. Typ. Max. Unit **Test Circuit** Operation point*1 S pole Вор 1.2 2.2 3.2 mΤ 4 _ Release point*2 N pole Brp -3.2 -2.2 -1.2 mT 4 _ Hysteresis width*3 B_{HYS} $B_{HYS} = B_{OP} - B_{RP}$ 4.4 mΤ 4

4. Product with $B_{OP} = 3.0 \text{ mT typ.}$

Table 10

			(Ta = +25	°C, V _{DD} = 1	12.0 V, V _{SS}	= 0 V unle	ss other	wise specified)
Item		Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Operation point*1	S pole	BOP	-	2.0	3.0	4.0	mT	4
Release point*2	N pole	BRP	-	-4.0	-3.0	-2.0	mT	4
Hysteresis width*3		BHYS	B _{HYS} = B _{OP} - B _{RP}	_	6.0	_	mT	4

*1. BOP: Operation point

BOP is the value of magnetic flux density when the output voltage (VOUT) changes after the magnetic flux density applied to this IC by the magnet (S pole) is increased (by moving the magnet closer).

Vout retains the status until a magnetic flux density of the N pole higher than BRP is applied.

*2. BRP: Release point

 B_{RP} is the value of magnetic flux density when the output voltage (V_{OUT}) changes after the magnetic flux density applied to this IC by the magnet (N pole) is increased (by moving the magnet closer).

 V_{OUT} retains the status until a magnetic flux density of the S pole higher than B_{OP} is applied.

*3. B_{HYS}: Hysteresis width

 B_{HYS} is the difference of magnetic flux density between B_{OP} and B_{RP} .

Remark The unit of magnetic density mT can be converted by using the formula 1 mT = 10 Gauss.

ABLIC Inc.

Test Circuits

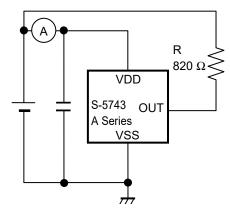


Figure 4 Test Circuit 1

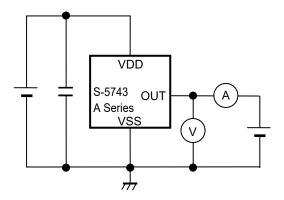
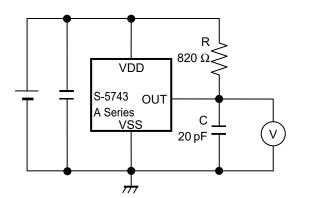
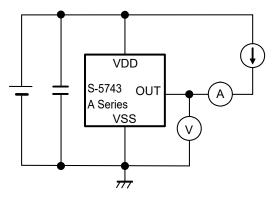
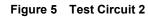


Figure 6 Test Circuit 3









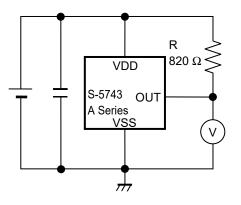
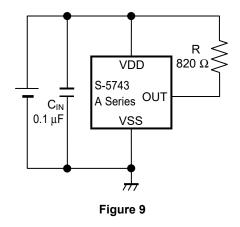


Figure 7 Test Circuit 4

Standard Circuit



Caution The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constants.

Operation

1. Direction of applied magnetic flux

This IC detects the magnetic flux density which is vertical to the marking surface. **Figure 10** shows the direction in which magnetic flux is being applied.

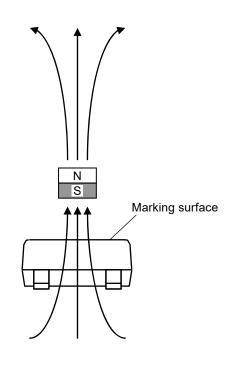


Figure 10

2. Position of Hall sensor

Figure 11 shows the position of Hall sensor.

The center of this Hall sensor is located in the area indicated by a circle, which is in the center of a package as described below.

The following also shows the distance (typ. value) between the marking surface and the chip surface of a package.

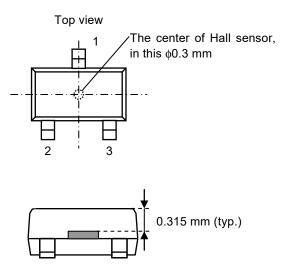


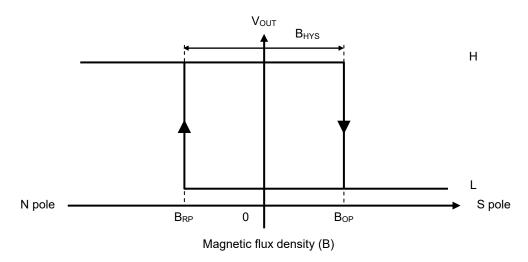
Figure 11

3. Basic operation

This IC changes the output voltage (V_{OUT}) according to the level of the magnetic flux density (N pole or S pole) and a polarity change applied by a magnet.

3. 1 Product with V_{OUT} = "L" at S pole detection

When the magnetic flux density of the S pole perpendicular to the marking surface exceeds the operation point (B_{OP}) after the S pole of a magnet is moved closer to the marking surface of this IC, V_{OUT} changes from "H" to "L". When the N pole of a magnet is moved closer to the marking surface of this IC and the magnetic flux density of the N pole is higher than the release point (B_{RP}), V_{OUT} changes from "L" to "H". In case of B_{RP} < B < B_{OP}, V_{OUT} retains the status. **Figure 12** shows the relationship between the magnetic flux density and V_{OUT}.





3. 2 Product with V_{OUT} = "H" at S pole detection

When the magnetic flux density of the S pole perpendicular to the marking surface exceeds B_{OP} after the S pole of a magnet is moved closer to the marking surface of this IC, V_{OUT} changes from "L" to "H". When the N pole of a magnet is moved closer to the marking surface of this IC and the magnetic flux density of the N pole is higher than B_{RP} , V_{OUT} changes from "H" to "L". In case of $B_{RP} < B < B_{OP}$, V_{OUT} retains the status. **Figure 13** shows the relationship between the magnetic flux density and V_{OUT} .

N pole B_{RP} 0 B_{OP} B_{OP} B



4. Timing chart

Figure 14 shows the timing chart at power-on for product with V_{OUT} = "L" at S pole detection. The initial output voltage at rising of power supply voltage (V_{DD}) is "H". In case of $B > B_{OP}$ at the time when the start up time (t_{PON}) is passed after rising of V_{DD}, this IC outputs "L". In case of $B < B_{OP}$ at the time when t_{PON} is passed after rising of V_{DD}, this IC outputs "L".

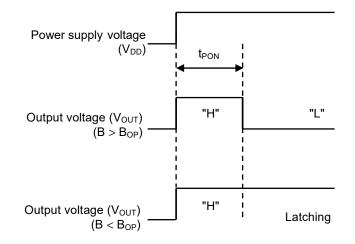
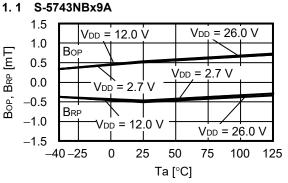


Figure 14

Precautions

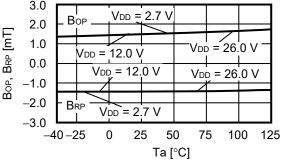
- If the impedance of the power supply is high, the IC may malfunction due to a supply voltage drop caused by feedthrough current. Take care with the pattern wiring to ensure that the impedance of the power supply is low.
- Note that the IC may malfunction if the power supply voltage rapidly changes. When the IC is used under the environment where the power supply voltage rapidly changes, it is recommended to judge the output voltage of the IC by reading it multiple times.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- Although this IC has a built-in output current limit circuit, it may suffer physical damage such as product deterioration under the environment where the absolute maximum ratings are exceeded.
- The application conditions for the power supply voltage, the pull-up voltage, and the pull-up resistor should not exceed the power dissipation.
- Large stress on this IC may affect the magnetic characteristics. Avoid large stress which is caused by the handling during or after mounting the IC on a board.
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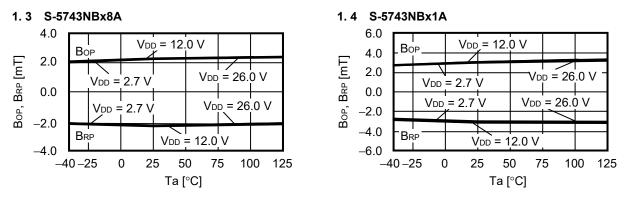
Characteristics (Typical Data)



1. Operation point, release point (B_{OP}, B_{RP}) vs. Temperature (Ta)

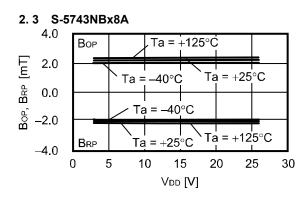
1. 2 S-5743NBx0A 3.0 BOP VDt



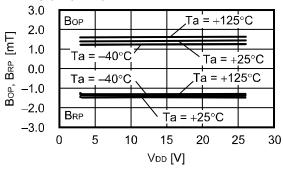


2. Operation point, release point (B_{OP} , B_{RP}) vs. Power supply voltage (V_{DD})

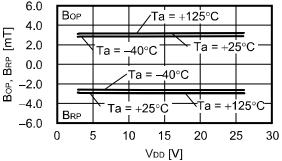
2.1 S-5743NBx9A 1.5 Вор Ta = +25°C Ta = +125°Ċ 1.0 [m] 0.5 Вкр 0.0 ,⊤a = –40°C Ta = -40°C ВоР, -0.5 -1.0 Ta = +125°C Ta = +25°C BRP -1.5 5 20 25 10 15 30 0 Vdd [V]



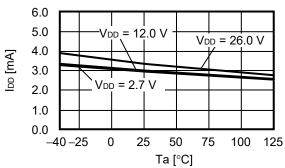
2.2 S-5743NBx0A



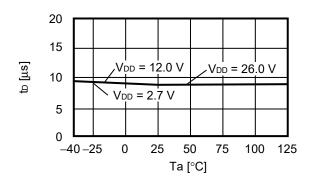




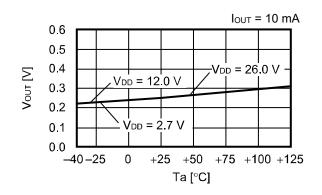
3. Current consumption (I_{DD}) vs. Temperature (Ta)



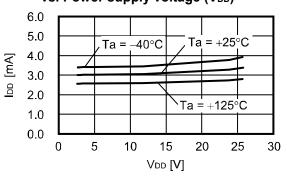
5. Output delay time (t_D) vs. Temperature (Ta)



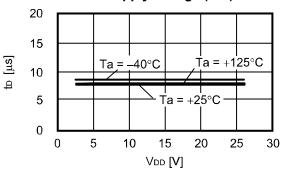
7. Output voltage (V_{OUT}) vs. Temperature (Ta)



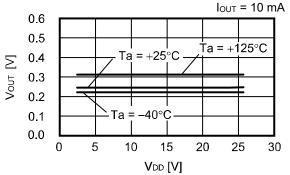
4. Current consumption (I_{DD}) vs. Power supply voltage (V_{DD})



 Output delay time (t_D) vs. Power supply voltage (V_{DD})

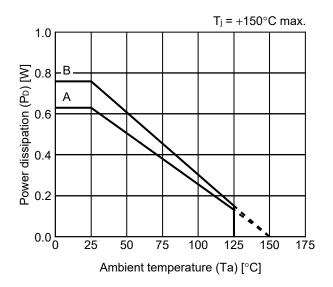


8. Output voltage (V_{OUT}) vs. Power supply voltage (V_{DD})



Power Dissipation

SOT-23-3S



Board	Power Dissipation (P _D)
А	0.63 W
В	0.76 W
С	_
D	_
E	_

SOT-23-3/3S/5/6 Test Board

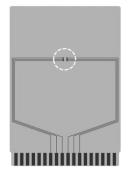
) IC Mount Area

(1) Board A



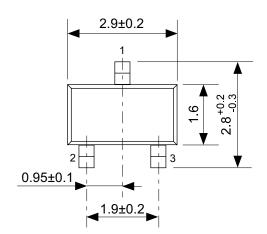
Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil la	ayer	2
	1	Land pattern and wiring for testing: t0.070
Copper foil layer [mm]	2	-
	3	-
4		74.2 x 74.2 x t0.070
Thermal via		-

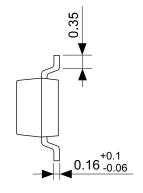
(2) Board B

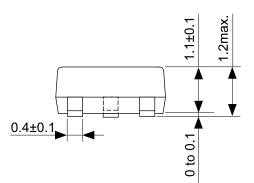


Item		Specification
Size [mm]		114.3 x 76.2 x t1.6
Material		FR-4
Number of copper foil layer		4
	1	Land pattern and wiring for testing: t0.070
Coppor foil lover [mm]	2	74.2 x 74.2 x t0.035
Copper foil layer [mm]	3	74.2 x 74.2 x t0.035
	4	74.2 x 74.2 x t0.070
Thermal via		-

No. SOT23x-A-Board-SD-2.0

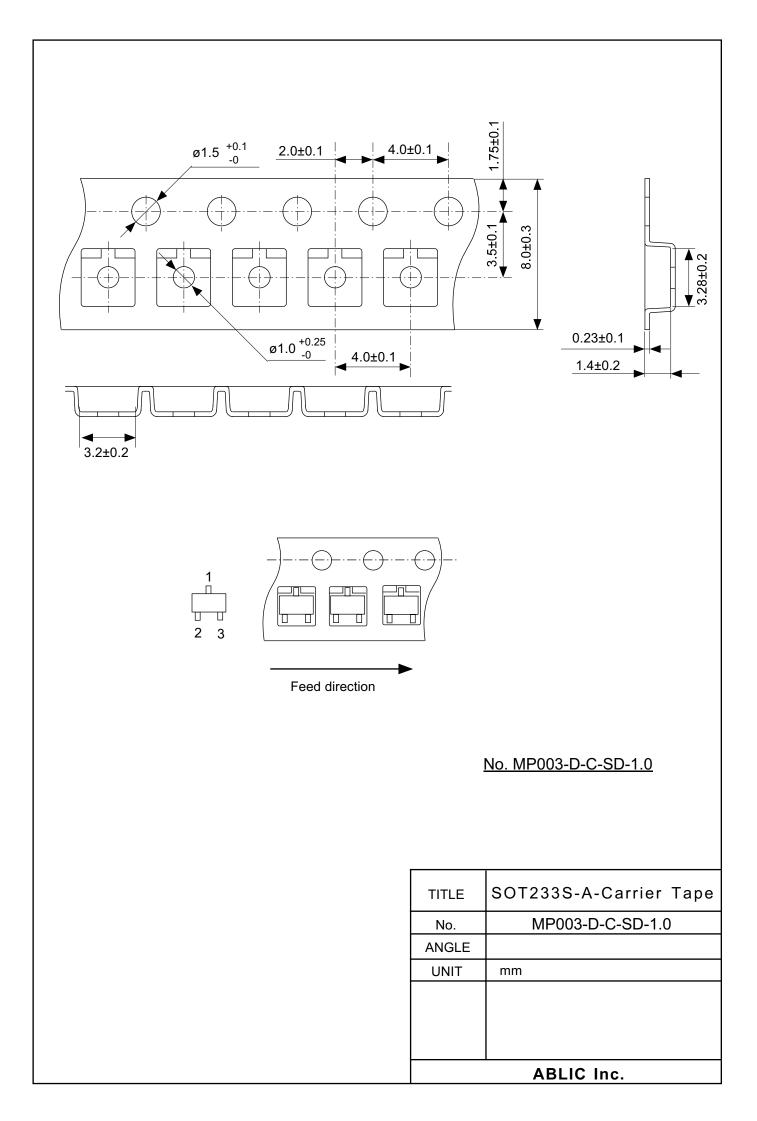


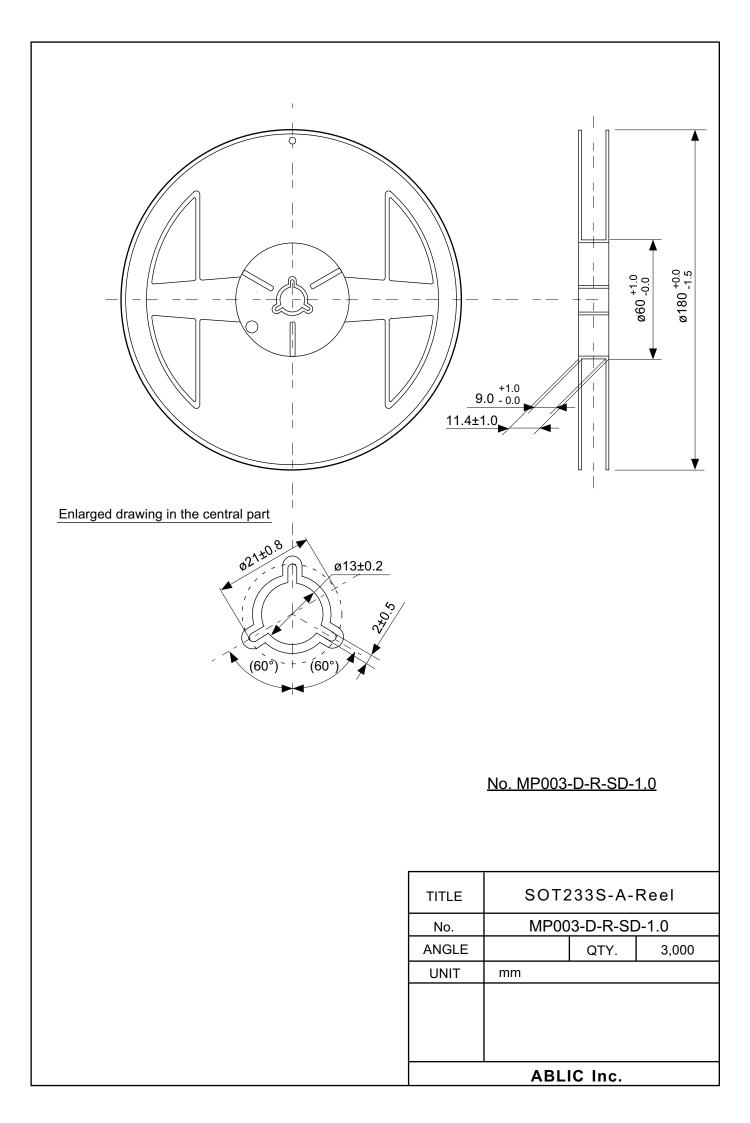




No. MP003-D-P-SD-1.1

TITLE	SOT233S-A-PKG Dimensions
No.	MP003-D-P-SD-1.1
ANGLE	\oplus
UNIT	mm
ABLIC Inc.	





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2.4-2019.07